



东莞市华远电子有限公司

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TO-92 Plastic-Encapsulate Transistors

2SD1616

TRANSISTOR (NPN)

FEATURE

Power dissipation

P_{CM} : 0.75 W ($T_{amb}=25$)

Collector current

I_{CM} : 1 A

Collector-base voltage

$V_{(BR)CBO}$: 60 V

Operating and storage junction temperature range

T_J, T_{stg} : -55 to +150

TO—92

1.EMITTER

2. COLLECTOR

3. BSAE



ELECTRICAL CHARACTERISTICS ($T_{amb}=25$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 10 \mu A$, $I_E = 0$	60		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 2 mA$, $I_B = 0$	50		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 10 \mu A$, $I_C = 0$	6		V
Collector cut-off current	I_{CBO}	$V_{CB} = 60V$, $I_E = 0$		0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 6V$, $I_C = 0$		0.1	μA
DC current gain	h_{FE1}	$V_{CE} = 2V$, $I_C = 100mA$	135	600	
	h_{FE2}	$V_{CE} = 2V$, $I_C = 1A$	81		
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_C = 1A$, $I_B = 50mA$		0.3	V
Base-emitter saturation voltage *	$V_{BE(sat)}$	$I_C = 1A$, $I_B = 50mA$		1.2	V
Base-emitter voltage *	V_{BE}	$V_{CE} = 2V$, $I_C = 50mA$		0.7	V
Transition frequency	f_T	$V_{CE} = 2V$, $I_C = 100mA$	100		MHz
Output capacitance	C_{ob}	$V_{CE} = 10V$, $I_E = 0$, $f = 1MHz$		25	pF
Turn on time	t_{on}	$V_{CC} = 10V$, $I_C = 100mA$, $I_{B1} = -I_{B2} = 10Ma$ $V_{be(off)} = -2 \sim -3V$		0.07 typ	ms
Storage time	t_s			0.95 typ	ms
Fall time	t_F			0.07 typ	ms

*pulse test : $PW=350\mu S$, $d=2\%$.

CLASSIFICATION OF h_{FE1}

Rank	Y	G	L
Range	135-270	200-400	300-600

Typical Characteristics

2SD1616

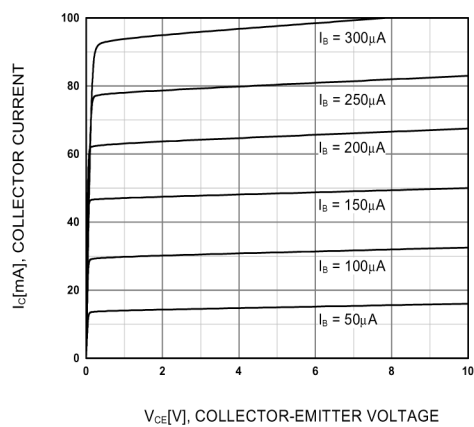


Figure 1. Static Characteristic

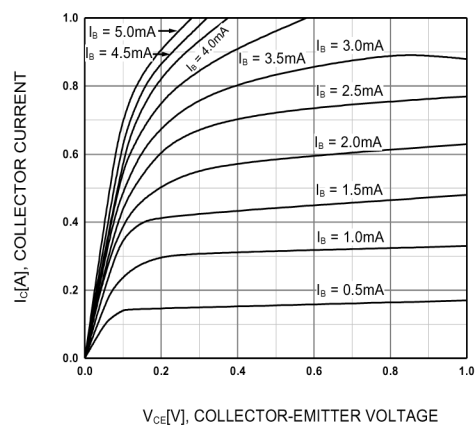


Figure 2. Static Characteristic

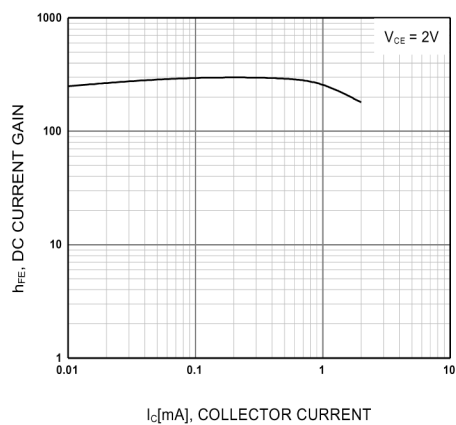
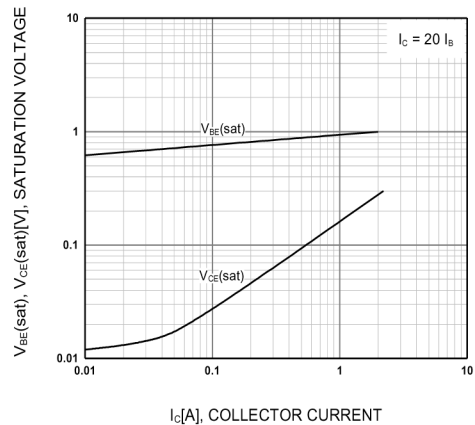


Figure 3. DC current Gain



**Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage**

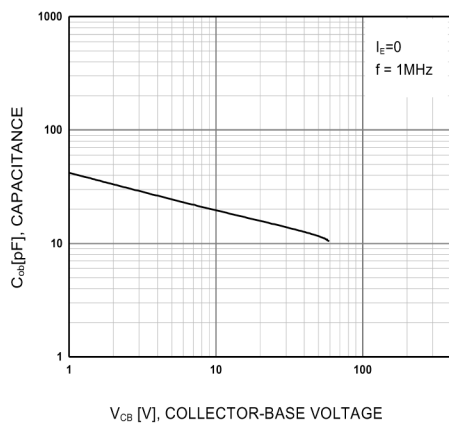


Figure 5. Collector Output Capacitance

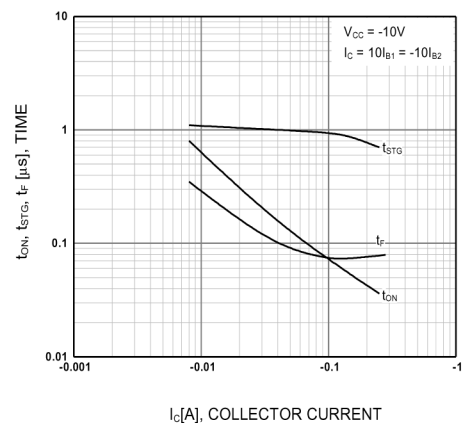


Figure 6. Switching Time

Typical Characteristics

2SD1616

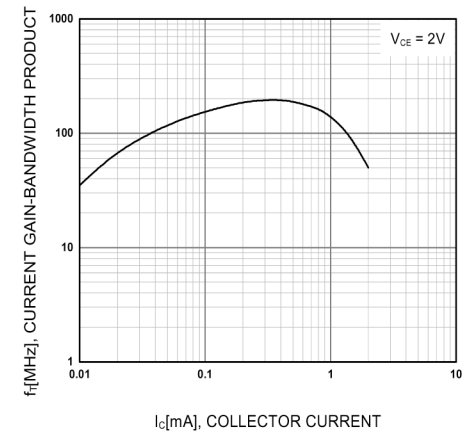


Figure 7. Current Gain Bandwidth Product

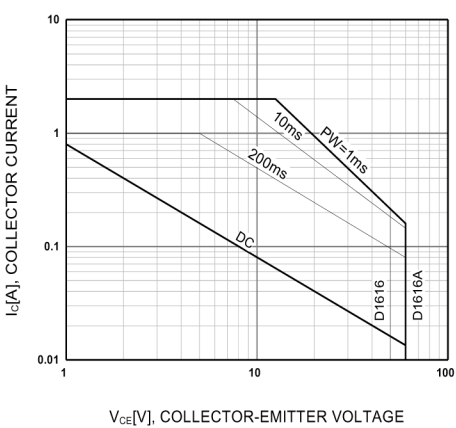


Figure 8. Safe Operating Area

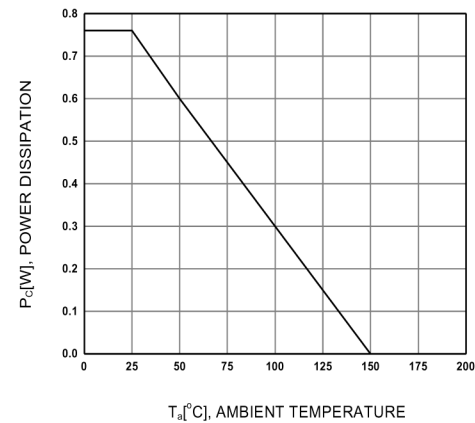
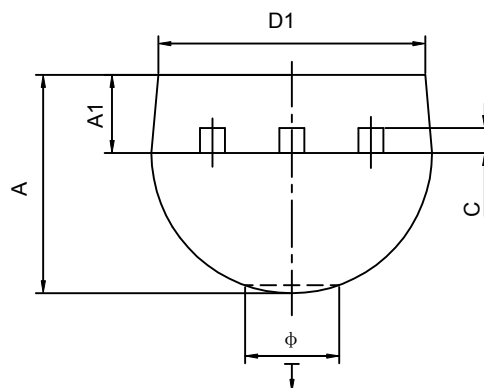
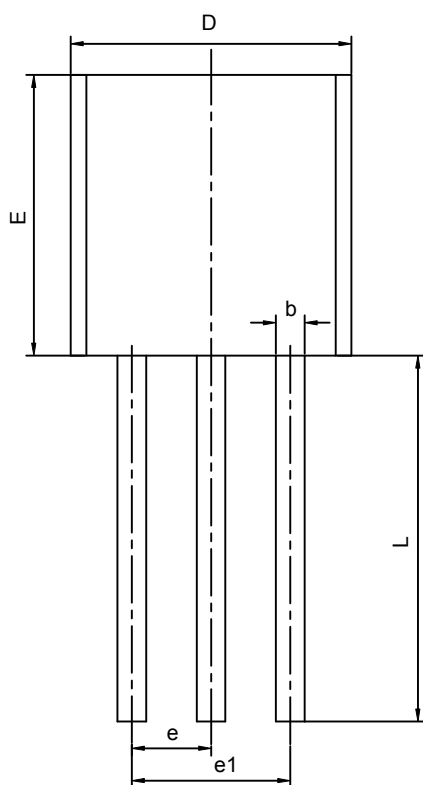


Figure 9. Power Derating

TO-92 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.400	4.700	0.173	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270TYP		0.050TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Ö		1.600		0.063
\downarrow	0.000	0.380	0.000	0.015